THYRISTOR(Through Hole/Isolated)

SMG16C60F

SanRex Thyristor **SMG16C60F** is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

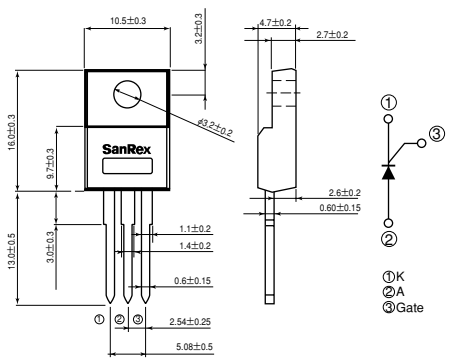
Typical Applications

- Home Appliances : Electric Blankets, Starter for FL, other control applications
- Industrial Use : SMPS, Solenoid for Breakers, Motor Controls, Heater Controls, other control applications

Features

- $I_{T(AV)}$=16A
- High Surge Current
- Low Voltage Drop
- Lead-Free Package

TO-220F



Identifying Code : S16C6F Unit : mm

■Maximum Ratings

(Tj=25℃ unless otherwise specified)

Symbol	Item	Reference	Ratings	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		600	V
V_{RSM}	Non-Repetitive Peak Reverse Voltage		720	V
V_{DRM}	Repetitive Peak Off-State Voltage		600	V
$I_{T(AV)}$	Average On-State Current	Single phase, half wave, 180°, conduction, Tc=58℃	16	A
$I_{T(RMS)}$	R.M.S. On-State Current	Single phase, half wave, 180°, conduction, Tc=58℃	25.1	A
I_{TSM}	Surge On-State Current	50Hz/60Hz, ½ cycle Peak value, non-repetitive	240/263	A
I^2t	I^2t		288	A^2S
P_{GM}	Peak Gate Power Dissipation		5	W
$P_{G(AV)}$	Average Gate Power Dissipation		0.5	W
I_{FGM}	Peak Gate Current		2	A
V_{FGM}	Peak Gate Voltage (Forward)		6	V
V_{RGM}	Peak Gate Voltage (Reverse)		10	V
V_{ISO}	Isolation Breakdown (R.M.S.)	A.C 1minute	1500	V
Tj	Operating Junction Temperature		−40～+125	℃
Tstg	Storage Temperature		−40～+150	℃
	Mass		2	g

■Electrical Characteristics

Symbol	Item	Reference	Ratings			Unit
			Min.	Typ.	Max.	
I_{DRM}	Repetitive Peak Off-State Current	Tj=125℃, $V_D=V_{DRM}$,			2	mA
I_{RRM}	Repetitive Peak Reverse Current	Tj=125℃, $V_R=V_{RRM}$,			2	mA
V_{TM}	Peak On-State Voltage	I_T=35A, Inst. measurement			1.5	V
I_{GT}	Gate Trigger Current	V_D=6V, R_L=10Ω			30	mA
V_{GT}	Gate Trigger Voltage				1.4	V
V_{GD}	Non-Trigger Gate Voltage	Tj=125℃, $V_D=½V_{DRM}$,	0.2			V
I_H	Holding Current			15		mA
Rth (j-c)	Thermal Resistance	Junction to case			3	℃/W

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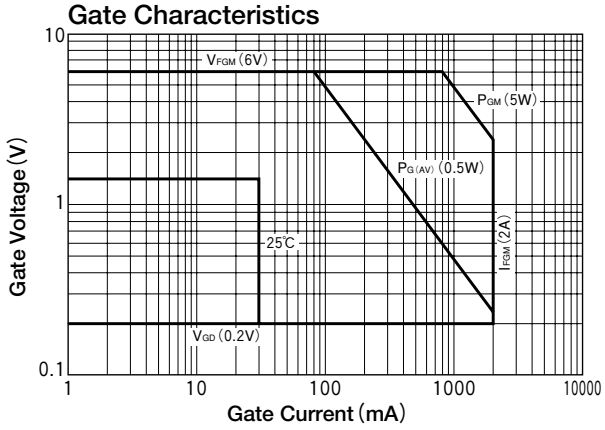
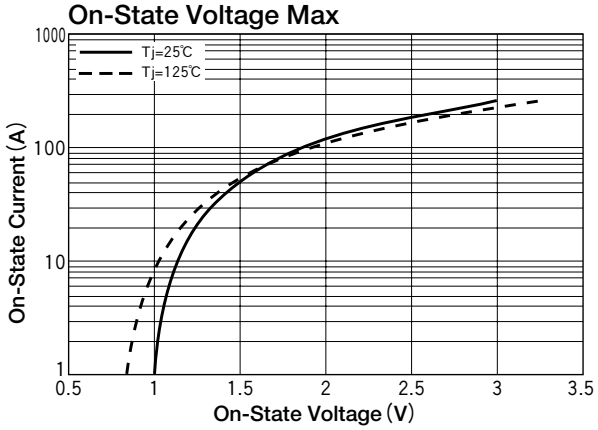
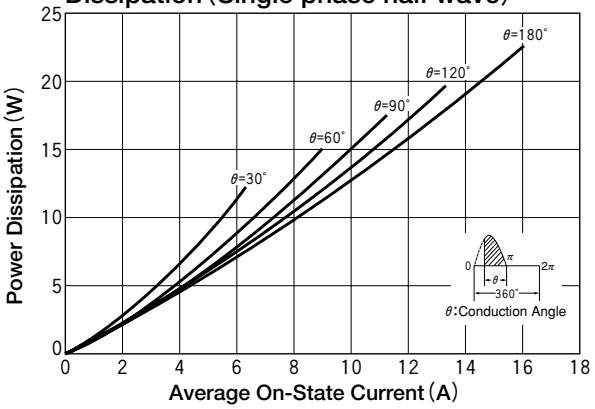
Gate Characteristics



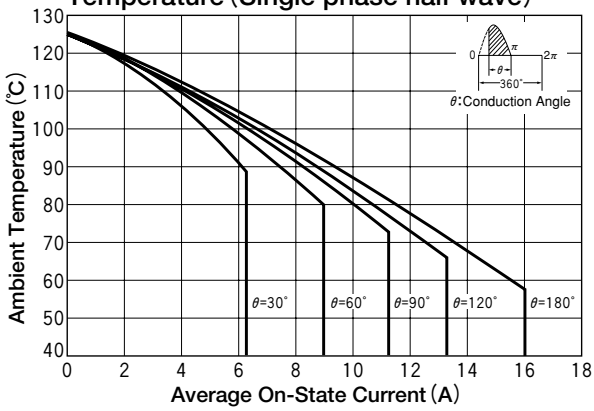
On-State Voltage Max



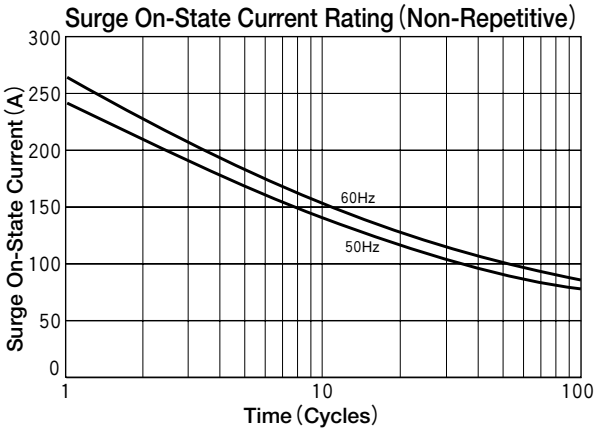
Average On-State Current vs Power Dissipation (Single phase half wave)



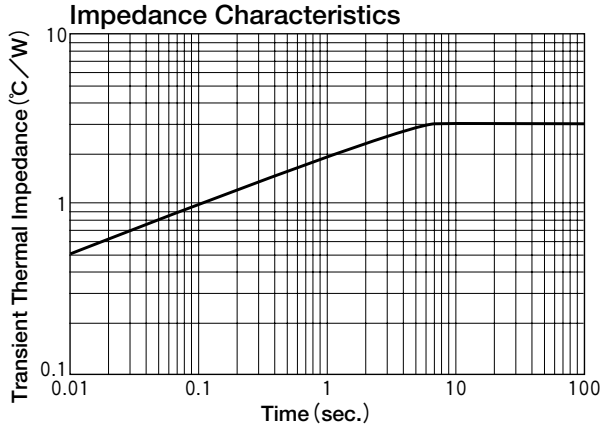
Average On-State Current vs Ambient Temperature (Single phase half wave)



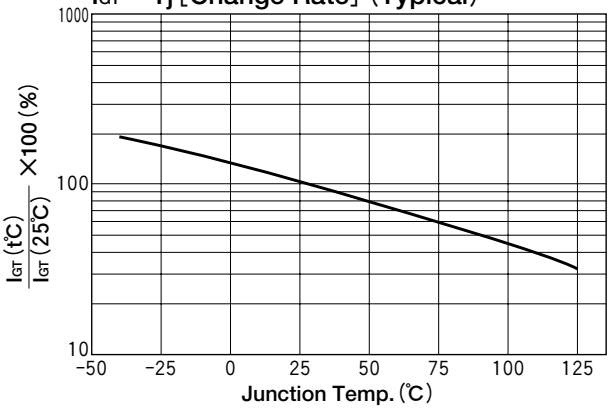
Surge On-State Current Rating (Non-Repetitive)



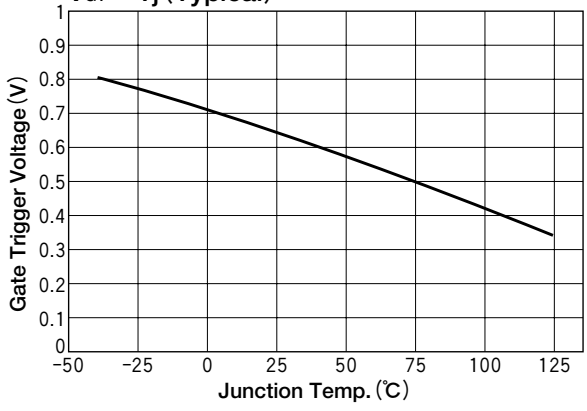
Maximum Transient Thermal Impedance Characteristics



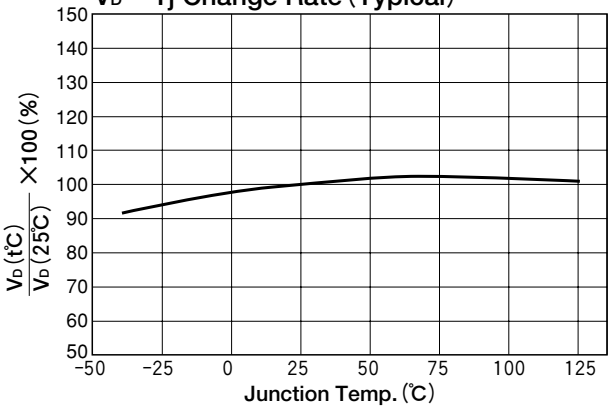
I_{GT} —Tj [Change Rate] (Typical)



V_{GT} —Tj (Typical)



V_D —Tj Change Rate (Typical)



V_R —T_j Change Rate (Typical)